

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



# Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China







# **Sensitive Gate Triacs**

# **Silicon Bidirectional Thyristors**

Designed for industrial and consumer applications for full wave control of AC loads such as appliance controls, heater controls, motor controls, and other power switching applications.

#### **Features**

- Sensitive Gate Allows Triggering by Microcontrollers and other Logic Circuits
- Blocking Voltage to 800 Volts
- On-State Current Rating of 12 Amperes RMS at 70°C
- High Surge Current Capability 90 Amperes
- Rugged, Economical TO-220AB Package
- Glass Passivated Junctions for Reliability and Uniformity
- Maximum Values of IGT, VGT and IH Specified for Ease of Design
- High Commutating di/dt 8.0 A/ms Minimum at 110°C
- Immunity to dV/dt 15 V/usec Minimum at 110°C
- Operational in Three Quadrants: Q1, Q2, and Q3
- These Devices are Pb-Free and are RoHS Compliant\*

#### **MAXIMUM RATINGS** (T<sub>J</sub> = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
$\begin{tabular}{lll} Peak Repetitive Off-State Voltage (Note 1) \\ (T_J = -40 to 110 ^{\circ}C, Sine Wave, \\ 50 to 60 Hz, Gate Open) & MAC12SM \\ & MAC12SN \\ \end{tabular}$	V <sub>DRM,</sub> V <sub>RRM</sub>	600 800	V
On-State RMS Current (All Conduction Angles; T <sub>C</sub> = 70°C)	I <sub>T(RMS)</sub>	12	Α
Peak Non-Repetitive Surge Current (One Full Cycle Sine Wave, 60 Hz, T <sub>J</sub> = 110°C)	I <sub>TSM</sub>	90	A
Circuit Fusing Consideration (t = 8.33 ms)	I <sup>2</sup> t	33	A <sup>2</sup> sec
Peak Gate Power (Pulse Width = 1.0 μsec, T <sub>C</sub> = 70°C)	P <sub>GM</sub>	16	W
Average Gate Power (t = 8.3 msec, T <sub>C</sub> = 70°C)	P <sub>G(AV)</sub>	0.35	W
Operating Junction Temperature Range	T <sub>J</sub>	-40 to 110	°C
Storage Temperature Range	T <sub>stg</sub>	-40 to 150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



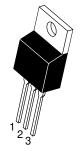
#### ON Semiconductor®

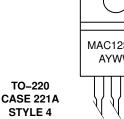
www.onsemi.com

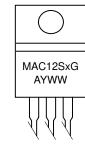
# **TRIACS** 12 AMPERES RMS 600 thru 800 VOLTS



#### MARKING **DIAGRAM**







= M, or N

= Assembly Location

= Year

= Work Week

= Pb-Free Package

PIN ASSIGNMENT			
1	Main Terminal 1		
2	Main Terminal 2		
3	Gate		
4	Main Terminal 2		

#### **ORDERING INFORMATION**

Device	Package	Shipping
MAC12SMG	TO-220 (Pb-Free)	50 Units / Rail
MAC12SNG	TO-220 (Pb-Free)	50 Units / Rail

<sup>1. (</sup>V<sub>DRM</sub> and V<sub>RRM</sub> for all types can be applied on a continuous basis. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Thermal Resistance, Junction-to-Case Junction-to-Ambient	${\sf R}_{ heta \sf JC} \ {\sf R}_{ heta \sf JA}$	2.2 62.5	°C/W
Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 10 Seconds	TL	260	°C

#### **ELECTRICAL CHARACTERISTICS** (T<sub>J</sub> = 25°C unless otherwise noted; Electricals apply in both directions)

Characteristic		Min	Тур	Max	Unit
Characteristic Symbol Min Typ Max Unit OFF CHARACTERISTICS					
Peak Repetitive Blocking Current $(V_D = Rated \ V_{DRM}, \ V_{RRM}; \ Gate \ Open) \\ T_J = 25^{\circ}C \\ T_J = 110^{\circ}C$	I <sub>DRM</sub> , I <sub>RRM</sub>	_ _	_ _	0.01 2.0	mA
ON CHARACTERISTICS	1	•	•	•	
Peak On-State Voltage (Note 2) (I <sub>TM</sub> = ±17 A)	V <sub>TM</sub>	-	-	1.85	V
Gate Trigger Current (Continuous dc) (V <sub>D</sub> = 12 V, R <sub>L</sub> = 100 $\Omega$ ) MT2(+), G(+) MT2(+), G(-) MT2(-), G(-)	l <sub>GT</sub>	- - -	1.5 2.5 2.7	5.0 5.0 5.0	mA
Holding Current (V <sub>D</sub> = 12 V, Gate Open, Initiating Current = ±200 mA)	I <sub>H</sub>	-	2.5	10	mA
Latching Current ( $V_D$ = 12 V, $I_G$ = 5 mA) MT2(+), G(+) MT2(+), G(-) MT2(-), G(-)	IL	- - -	3.0 5.0 3.0	15 20 15	mA
Gate Trigger Voltage (Continuous dc) (V <sub>D</sub> = 12 V, R <sub>L</sub> = 100 $\Omega$ ) MT2(+), G(+) MT2(+), G(-) MT2(-), G(-)	V <sub>GT</sub>	0.45 0.45 0.45	0.68 0.62 0.67	1.5 1.5 1.5	V
DYNAMIC CHARACTERISTICS	-	•	-	•	
Critical Rate of Change of Commutating Current ( $V_D=400~V,~I_{TM}=3.5~A,~Commutating~dV/dt=10~V/\mu s,~Gate~Open,~T_J=110^{\circ}C,~f=500~Hz,~Snubber:~Cs=0.01~\mu f,~Rs=15~\Omega)$	(di/dt) <sub>C</sub>	8.0	10	_	A/ms
Critical Rate of Rise of Off-State Voltage ( $V_D = 67\% \ V_{DRM}$ , Exponential Waveform, $R_{GK} = 1 \ K\Omega$ , $T_J = 110^{\circ}C$ )	dV/dt	15	40	-	V/μs

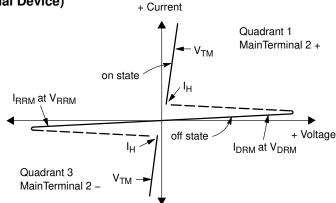
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 2. Pulse Test: Pulse Width  $\leq$  2.0 ms, Duty Cycle  $\leq$  2%.

Repetitive Critical Rate of Rise of On-State Current

IPK = 50 A; PW = 40  $\mu$ sec; diG/dt = 1 A/ $\mu$ sec; lgt = 100 mA; f = 60 Hz

#### **Voltage Current Characteristic of Triacs** (Bidirectional Device)

Symbol	Parameter
$V_{DRM}$	Peak Repetitive Forward Off State Voltage
I <sub>DRM</sub>	Peak Forward Blocking Current
V <sub>RRM</sub>	Peak Repetitive Reverse Off State Voltage
I <sub>RRM</sub>	Peak Reverse Blocking Current
$V_{TM}$	Maximum On State Voltage
I <sub>H</sub>	Holding Current

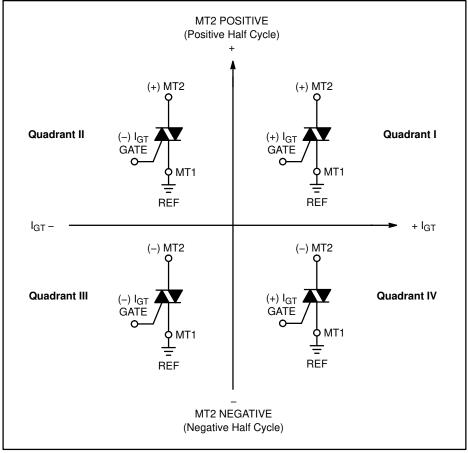


di/dt

10

A/μs

#### **Quadrant Definitions for a Triac**



All polarities are referenced to MT1.

With in-phase signals (using standard AC lines) quadrants I and III are used.

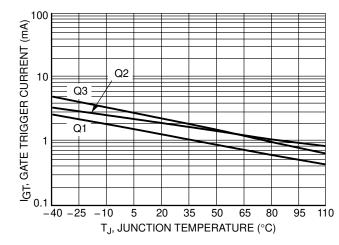


Figure 1. Typical Gate Trigger Current versus Junction Temperature

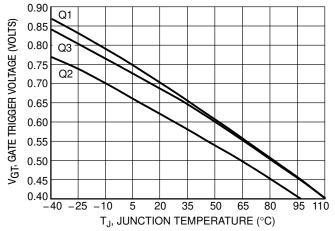
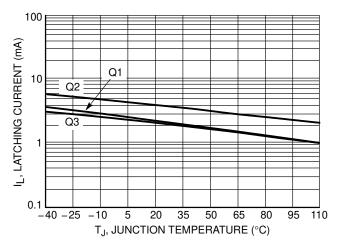


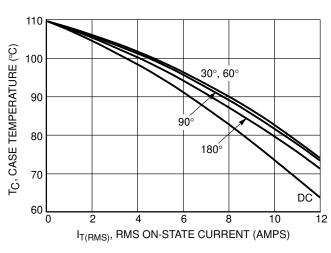
Figure 2. Typical Gate Trigger Voltage versus Junction Temperature



100 (YELL) 10 HT2 Positive 10 MT2 Positive 10 MT2 Negative 10 TJ, JUNCTION TEMPERATURE (°C)

Figure 3. Typical Latching Current versus Junction Temperature

Figure 4. Typical Holding Current versus Junction Temperature



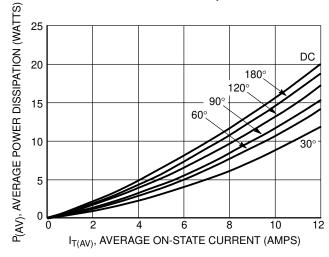
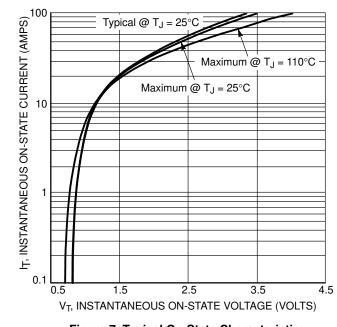


Figure 5. Typical RMS Current Derating

Figure 6. On-State Power Dissipation



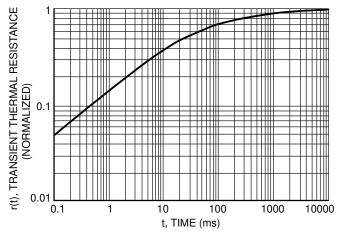
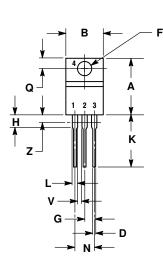


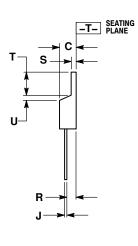
Figure 8. Typical Thermal Response

Figure 7. Typical On-State Characteristics

#### PACKAGE DIMENSIONS

TO-220 CASE 221A-09 **ISSUE AH** 





- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE

MULIMETERS

	INC	HES	MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.570	0.620	14.48	15.75	
В	0.380	0.415	9.66	10.53	
С	0.160	0.190	4.07	4.83	
D	0.025	0.038	0.64	0.96	
F	0.142	0.161	3.61	4.09	
G	0.095	0.105	2.42	2.66	
Н	0.110	0.161	2.80	4.10	
J	0.014	0.024	0.36	0.61	
K	0.500	0.562	12.70	14.27	
L	0.045	0.060	1.15	1.52	
N	0.190	0.210	4.83	5.33	
Q	0.100	0.120	2.54	3.04	
R	0.080	0.110	2.04	2.79	
S	0.045	0.055	1.15	1.39	
T	0.235	0.255	5.97	6.47	
U	0.000	0.050	0.00	1.27	
٧	0.045		1.15		
Z		0.080		2.04	

STYLE 4:

PIN 1. MAIN TERMINAL 1

- MAIN TERMINAL 2 2.
- 3. GATE
- MAIN TERMINAL 2

ON Semiconductor and the 👊 are registered trademarks of Semiconductor Components Industries, LLC (SCILLC) or its subsidiaries in the United States and/or other countries. ON Semiconductor and the war are registered trademarks of Semiconductor Components Industries, LLC (SCILLC) or its subsidiaries in the United States and/or other countries. SCILLC owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of SCILLC's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim of personal injury or death associated w expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

#### **PUBLICATION ORDERING INFORMATION**

#### LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA

Phone: 303–675–2175 or 800–344–3860 Toll Free USA/Canada

Fax: 303–675–2176 or 800–344–3867 Toll Free USA/Canada

Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free

Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910

Japan Customer Focus Center

Phone: 81-3-5817-1050

ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative